

FDMS86500L

Data Sheet

FAIRCHILD SEMICONDUCTOR FDMS86500L MOSFET Transistor, N Channel, 80A, 60V, 0.0021Ω , 10V, 1.8V

Manufacturers

ON Semiconductor, LLC

Package/Case

Power 56

Product Type

Transistors

RoHS

Green

Ima

Images are for reference only

Please submit RFQ for FDMS86500L or Email to us: sales@ovaga.com We will contact you in 12 hours.

<u>RFQ</u>

General Description

This N-Channel MOSFET has been designed specifically to improve the overall efficiency and to minimize switch node ringing of DC/DC converters using either synchronous or conventional switching PWM controllers. It has been optimized for low gate charge, low RDS(on), fast switching speed and body diode reverse recovery performance.

Features Application

Max = 10 V,>

Max = 4.5 V. >

advanced Package and Silicon combination for low rDS(on) and high efficiency

Next generation enhanced body diode technology, engineered for soft recovery

MSL1 robust package design

100% UIL tested

RoHS Compliant

Related Products



FDC645N
ON Semiconductor, LLC



ON Semiconductor, LLC SSOT-6

FDC637BNZ



FDC6305N

SSOT-6

ON Semiconductor, LLC SSOT-6



FDD8647L

ON Semiconductor, LLC TO-252-3



FDD5N50NZTM

ON Semiconductor, LLC TO-252



FDC602P

ON Semiconductor, LLC SOT163



FDB070AN06A0

ON Semiconductor, LLC TO-263



FDD3670

ON Semiconductor, LLC TO-252AA